

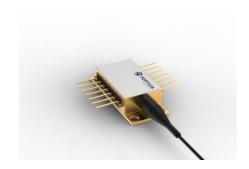
Revision 0.90 2023-05-25

SINGLE FREQUENCY LASER DFB Laser



General Product Information

Product	Application
Tunable 760 nm DFB Laser	Spectroscopy
with hermetic 14-Pin Butterfly Housing (RoHS compliant)	Metrology
including Monitor Diode, Thermoelectric Cooler and Thermistor	Oxygen Detection
with PM Fiber, integrated μ-Isolator and Angled Physical Contact (APC)	



Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	Ts	° C	-40		85
Operational Temperature at Case	T_C	° C	-15		70
Operational Temperature at Chip	T_{chip}	° C	10		50
Forward Current	I _F	mA			180
Reverse Voltage	V_{R}	V			2
Output Power	P_{opt}	mW			14
TEC Current	I _{TEC}	Α			1,4
TEC Voltage	V_{TEC}	V			4,8

Measurement Conditions / Comments

Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.

Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T _{case}	° C	5		60
Operational Temperature at Chip	T_{chip}	° C	10		35
Forward Current	I _F	mA			170
Output Power	P_{opt}	mW	4		12

leasurement Conditions / Comments	
	_
x fiber	

Characteristics = 25° C at BOL

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ_{C}	nm	759,9	760,9	761,9
Target Wavelength	λ_{T}	nm		760,9	
Mode-hop free Tuning Range	$\Delta \lambda_{tune}$	pm	40		
Sidemode Suppression Ratio	SMSR	dB	30	45	
Temp. Coefficient of Wavelength	$d\lambda / dT$	nm/K		0,06	
Current Coefficient of Wavelength	$d\lambda$ / dI	nm/mA		0,002	

reached betweem 15° and 35° C at P = 12 mW
at target wawevelength
Popt = 12 mW



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Symbol	Unit	min	typ	max
I _{LD}	mA			170
η	mW/mA		0,1	
I_{th}	mA			70
PER	dB		20	
	I _{LD} η I _{th}	$\begin{array}{cc} I_{LD} & mA \\ \eta & mW/mA \\ I_{th} & mA \end{array}$	I _{LD} mA η mW/mA I _{th} mA	I _{LD} mA η mW/mA 0,1 I _{th} mA

Monitor Diode				
Parameter	Symbol Unit	min	typ	max
Monitor Detector Responsivity	I _{mon} / P _{or} μA/mW	10		800

Measurement Conditions / Comments	
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Parameter	Symbol	Unit	min	typ	max
Current	I _{TEC}	Α		0,4	
Voltage	U_{TEC}	V		1,5	
Power Dissipation (total loss at case)	P _{loss}	W		0,5	
Temperature Difference	ΔΤ	K			50

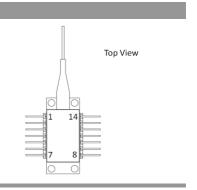
Measurement Conditions / Comments
Popt = 12 mW, ΔT = 30 K
Popt = 12 mW, ΔT = 30 K
Popt = 12 mW, ΔT = 30 K
Popt = 12 mW, ΔT = Tcase - TLD

Parameter	Symbol	Unit	min	typ	max
Resistance	R	kW		10	
Beta Coefficient	b			3892	
Steinhart & Hart Coefficient A	Α		1.	.1293 x 10	. 3
Steinhart & Hart Coefficient B	В		2.	.3410 x 10	- 4
Steinhart & Hart Coefficient C	С		8.	.7755 x 10	-8

Thermistor (Standard NTC Type)

Measurement Conditions / Comments		
25° C		
0° 50° C		

n Assignment	
1 Thermoelectric Cooler (+)	14 Thermoelectric Cooler (-)
2 Thermistor	13 Case
3 Photo Diode Anode	12 not connected
4 Photo Diode Cathode	11 Laser Diode Cathode
5 Thermistor	10 Laser Diode Anode
6 not connected	9 not connected
7 not connected	8 not connected



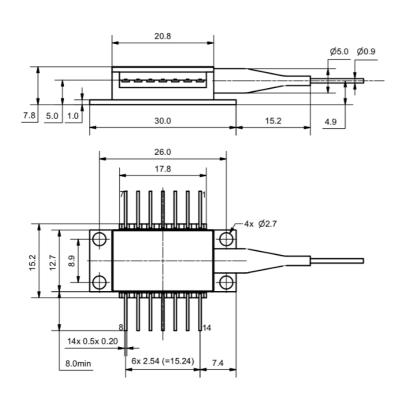


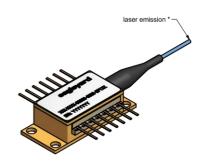
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Package Drawings





AIZ-16-0222-1415

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Parameter	
PM Fiber	900 / 125 / 5.5 μm, UV/Polyester-elastomer Coating (I = 1 +/-0.1 m)
Connector	FC/APC (narrow key / 2mm)

Measurement Conditions / Comments



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Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.



A laser diode is sensitive against optical feedback, so an optical isolator may be required in order to avoid any disturbance of the emission spectrum. Operating at moderate temperatures on proper heat sinks will contribute to a long lifetime of the diode.



INVISIBLE LASER RADIATION
TO DIRECT OR SCATTERED RADIATION CLASS 4
LASER REPODUCT
AVOID EYE OR SKIN EXPOSUR
WAVELENGTH 760 nm
MAX. OUTPUT POWER 14 mW

IEC-60825-1

Each laser diode will come with an individual test protocol verifying the parameters given in this document.

Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.





Complies with 21 CFR 1040.10 and 1040.40

Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.